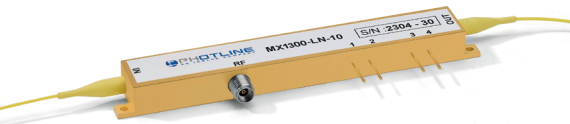


## MX1300-LN series

1310 nm band Intensity Modulators

### PHOTLINE MODULATOR



#### FEATURES

- 1310 nm specific waveguides and fibers
- X-cut for high stability
- Low drive voltage
- Low insertion loss

#### APPLICATIONS

- Up to 44 Gb/s digital communications
- General purpose intensity modulation
- Test and measurement

#### OPTIONS

- Analog version
- 1060 nm, 850 nm band versions

#### RELATED EQUIPMENTS

- Choice of RF drivers
- MBC-DG Automatic Bias Controllers
- ModBox-1310nm-44Gb/s-NRZ

The Photline MX1300-LN series are lithium niobate (LiNbO<sub>3</sub>) intensity modulators specially designed for operation in the 1310 nm wavelength band. Thanks to their 1310 nm optimized optical waveguides and their 1310 nm selected fibers, the MX1300-LN can be claimed genuine 1310 nm intensity modulators.

The X-cut design of these Mach-Zehnder modulator confers them an unmatched stability in a wide range of operational conditions, as well as a zero chirp performance. iXBlue proprietary waveguide design offers a low insertion loss combined with a high contrast. Thanks to their low V<sub>p</sub>, the MX1300 series are ideally suited for 10-12.5 Gb/s up to 50 Gb/s optical transmission with NRZ, RZ, DPSK, Duo Binary modulation formats and are key devices for a large variety of applications.

#### MX1300-LN-10 Performance Highlights

Parameter	Min	Typ	Max	Unit
Operating wavelength	1290	-	1330	nm
Insertion loss	-	3.5	-	dB
Electro-optical bandwidth	-	12	-	GHz
V <sub>π</sub> RF @50 kHz	-	4	-	V

Specifications given at 25 °C, 50 Ω, 1310 nm.

#### MX1300-LN-20 Performance Highlights

Parameter	Min	Typ	Max	Unit
Operating wavelength	1290	-	1330	nm
Insertion loss	-	3.5	-	dB
Electro-optical bandwidth	-	25	-	GHz
V <sub>π</sub> RF @50 kHz	-	4	-	V

Specifications given at 25 °C, 50 Ω, 1310 nm.

#### MX1300-LN-40 Performance Highlights

Parameter	Min	Typ	Max	Unit
Operating wavelength	1290	-	1330	nm
Insertion loss	-	3.5	-	dB
Electro-optical bandwidth	-	30	-	GHz
V <sub>π</sub> RF @50 kHz	-	4	-	V

Specifications given at 25 °C, 50 Ω, 1310 nm.

## MX1300-LN-10

12 GHz Intensity modulator

### Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optic bandwidth	$S_{21}$	RF electrodes, -3dB from 2 GHz	10	12	-	GHz
Ripple $S_{21}$	$\Delta S_{21}$	RF electrodes	-	0.5	1	dB
Electrical return loss	$S_{11}$	RF electrodes, $f < 10$ GHz	-	-15	-10	dB
$V_{\pi}$ RF @50 kHz	$V_{\pi RF_{50\text{ kHz}}}$	RF electrodes	-	4	5	V
$V_{\pi}$ RF @10 Gb/s PRBS	$V_{\pi RF_{10\text{ Gb/s}}}$	RF electrodes	-	4.7	5.7	V
$V_{\pi}$ DC electrodes	$V_{\pi DC}$	DC electrodes	-	5.5	6	V
RF input impedance	$Z_{in-RF}$	-	-	50	-	$\Omega$
DC input impedance	$Z_{in-DC}$	-	1	-	-	$M\Omega$

 50  $\Omega$  RF input

### Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-	Lithium Niobate X-Cut Y-Prop			
Operating wavelength	$\lambda$	-	1290	1310	1330	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	22	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	$\alpha$	-	-0.1	0	0.1	-

All specifications given at 25°C, 1310 nm, unless differently specified

### Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input power	$EP_{in}$	-	28	dBm
Bias voltage	$V_{bias}$	-20	+20	V
Optical input power	$OP_{in}$	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

## MX1300-LN-20

25 GHz Intensity modulator

### Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optic bandwidth	$S_{21}$	RF electrodes, -3dB from 2 GHz	20	25	-	GHz
Ripple $S_{21}$	$\Delta S_{21}$	RF electrodes	-	0.5	1	dB
Electrical return loss	$S_{11}$	RF electrodes, $f < 20$ GHz	-	-15	-10	dB
$V\pi$ RF @50 kHz	$V\pi_{RF_{50\text{ kHz}}}$	RF electrodes	-	4	5	V
$V\pi$ RF @20 Gb/s PRBS	$V\pi_{RF_{20\text{ Gb/s}}}$	RF electrodes	-	5.5	6	V
$V\pi$ DC electrodes	$V\pi_{DC}$	DC electrodes	-	5.5	6	V
RF input impedance	$Z_{in-RF}$	-	-	50	-	$\Omega$
DC input impedance	$Z_{in-DC}$	-	1	-	-	M $\Omega$

 50  $\Omega$  RF input

### Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-	Lithium Niobate X-Cut Y-Prop			
Operating wavelength	$\lambda$	-	1290	1310	1330	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	22	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	$\alpha$	-	-0.1	0	0.1	-

All specifications given at 25°C, 1310 nm, unless differently specified

### Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input power	$EP_{in}$	-	28	dBm
Bias voltage	$V_{bias}$	-20	+20	V
Optical input power	$OP_{in}$	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

## MX1300-LN-40

40 GHz Intensity modulator

### Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optic bandwidth	$S_{21}$	RF electrodes, -3dB from 2 GHz	28	30	-	GHz
Ripple $S_{21}$	$\Delta S_{21}$	RF electrodes	-	0.5	1	dB
Electrical return loss	$S_{11}$	RF electrodes, $f < 30$ GHz	-	-15	-10	dB
$V_{\pi}$ RF @50 kHz	$V_{\pi RF_{50\text{ kHz}}}$	RF electrodes	-	4	5	V
$V_{\pi}$ DC electrodes	$V_{\pi DC}$	DC electrodes	-	5.5	6	V
RF input impedance	$Z_{in-RF}$	-	-	50	-	$\Omega$
DC input impedance	$Z_{in-DC}$	-	1	-	-	M $\Omega$

 50  $\Omega$  RF input

### Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-	Lithium Niobate X-Cut Y-Prop			
Operating wavelength	$\lambda$	-	1290	1310	1330	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	22	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	$\alpha$	-	-0.1	0	0.1	-

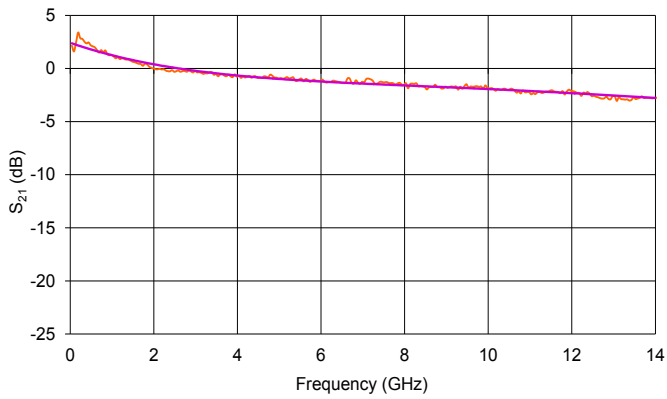
All specifications given at 25°C, 1310 nm, unless differently specified

### Absolute Maximum Ratings

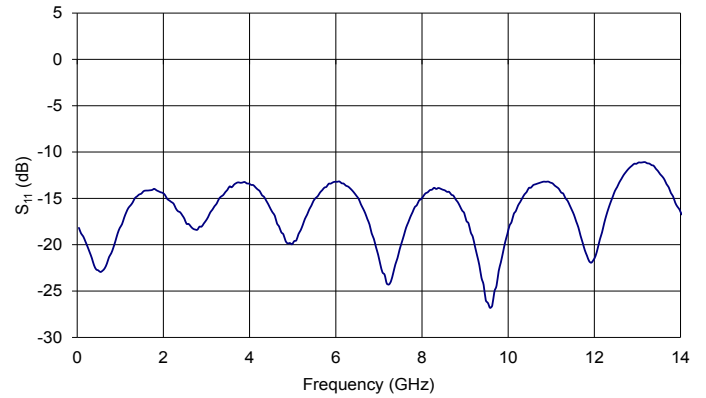
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Parameter	Symbol	Min	Max	Unit
RF input power	$EP_{in}$	-	28	dBm
Bias voltage	$V_{bias}$	-20	+20	V
Optical input power	$OP_{in}$	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

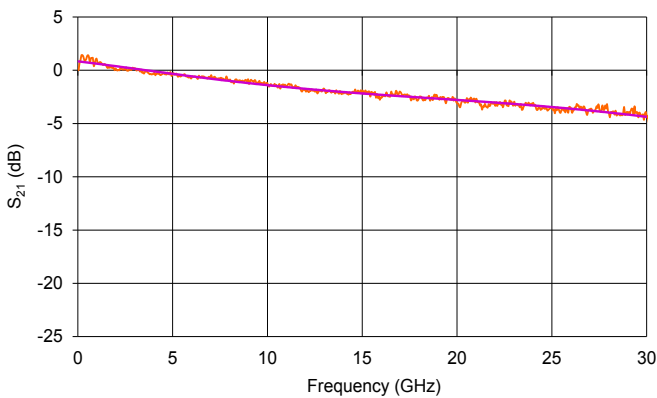
**MX1300-LN-10 Typical  $S_{21}$  Curve**



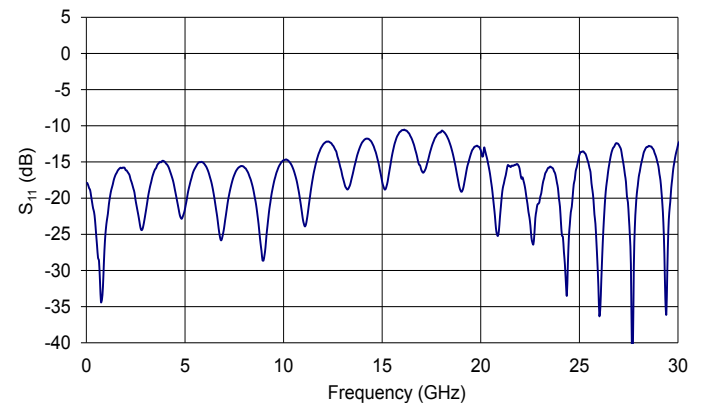
**MX1300-LN-10 Typical  $S_{11}$  Curve**



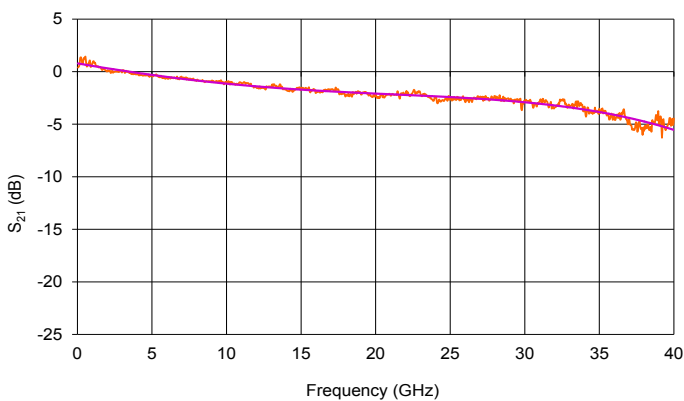
**MX1300-LN-20 Typical  $S_{21}$  Curve**



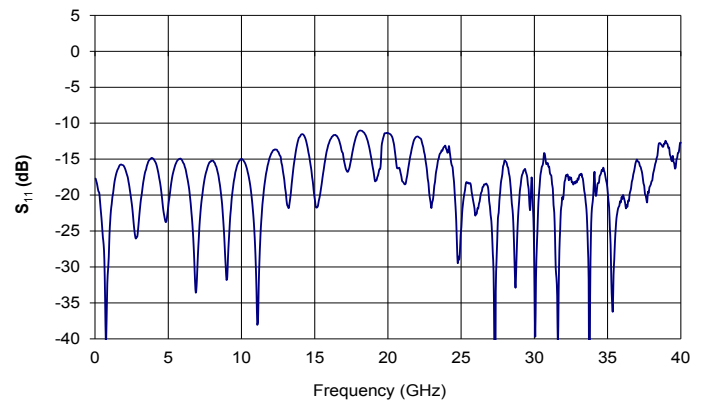
**MX1300-LN-20 Typical  $S_{11}$  Curve**



**MX1300-LN-40 Typical  $S_{21}$  Curve**

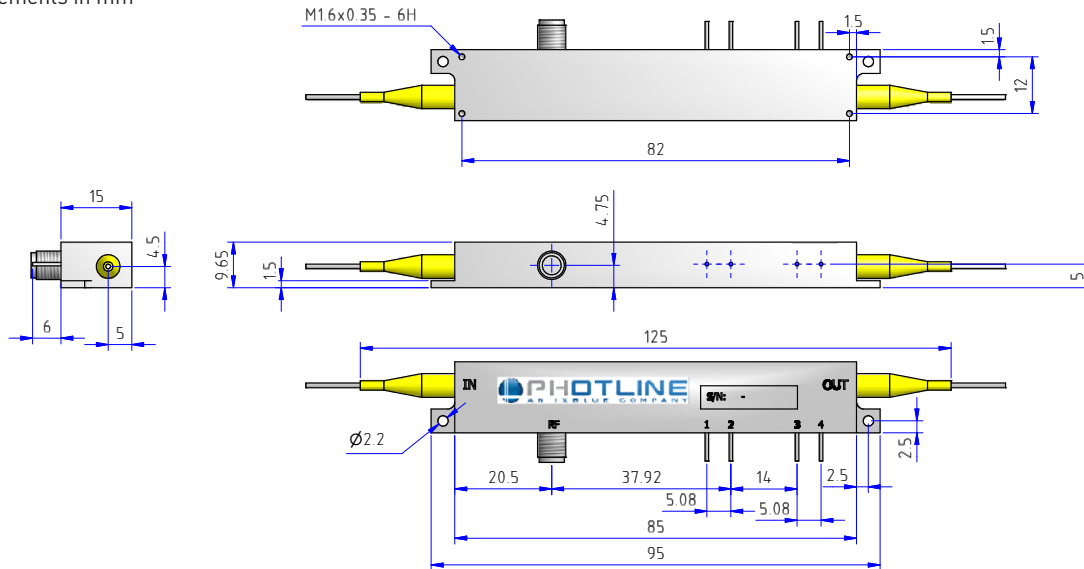


**MX1300-LN-40 Typical  $S_{11}$  Curve**



### Mechanical Diagram and Pinout

All measurements in mm



Port	Function	Note
IN	Optical input port	Polarization maintaining 1310 nm Corning PM13-U25D length : 1.5 meter, buffer diameter : 900 um
OUT	Optical output port	Polarization maintaining 1310 nm Corning PM13-U25D length : 1.5 meter, buffer diameter : 900 um
RF	RF input port	MX-LN-10: Wiltron female K (SMA compatible) MX-LN-20: Wiltron female K or V (optional) MX-LN-40: Wiltron female V
1	Ground	Pin feed through diameter 1.0 mm
2	DC	Pin feed through diameter 1.0 mm
3, 4	Photodiode cathode, anode	Pin feed through diameter 1.0 mm

### Ordering information

## MX1300-LN-BW-XX-Y-Z-AB-CD

**BW = Bandwidth** : 10 10 GHz 20 20 GHz 40 40 GHz  
**XX = Internal photodiode** : 00 Not integrated PD PD Integrated  
**Y = Input fiber** : P Polarization maintaining S Standard single mode  
**Z = Output fiber** : P Polarization maintaining S Standard single mode  
**AB = Input connector** : 00 bare fiber FA FC/APC FC FC/SPC  
**CD = Output connector** : 00 bare fiber FA FC/APC FC FC/SPC  
 Note : optical connectors are Seikoh-Giken with narrow key or equivalent

### About us

iXBlue Photonics includes iXBlue iXFiber brand that produces specialty optical fibers and Bragg gratings based fiber optics components and iXBlue Photline brand that provides optical modulation solutions based on the company lithium niobate (LiNbO<sub>3</sub>) modulators and RF electronic modules.

iXBlue Photonics serves a wide range of industries : sensing and instruments, defense, telecommunications, space and fiber lasers as well as research laboratories all over the world.

3, rue Sophie Germain  
 25 000 Besançon - FRANCE  
 Tel. : +33 (0) 381 853 180 - Fax : + 33 (0) 381 811 557

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